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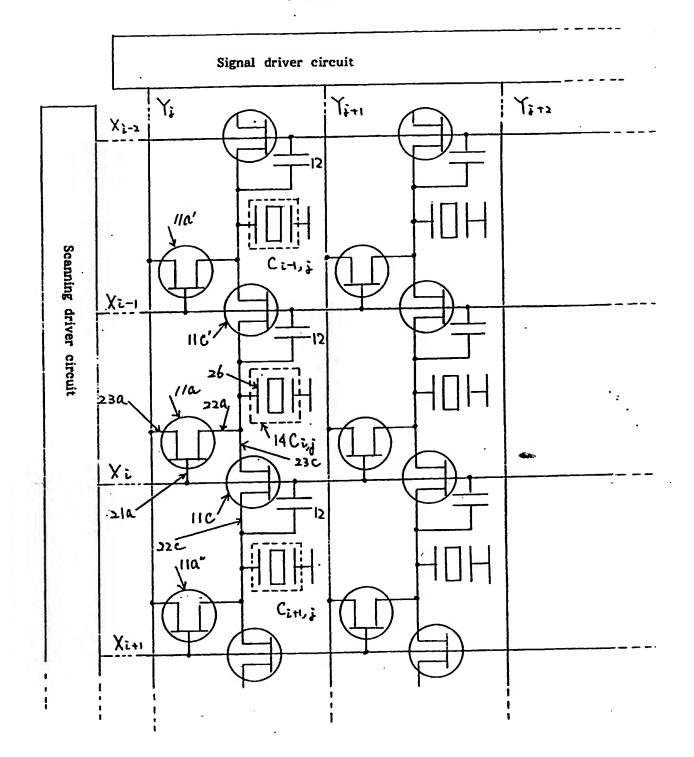
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- (54) Liquid crystal display device.
- An improved arrangement of a liquid crystal display device is provided in which the redundancy of known but unwanted TFT (thin film transistor) defect is suppressed so that the yield per finished liquid crystal display device products can be increased without declination in the picture quality. Each pixel of the liquid crystal display device arranged at an intersection of one of scanning lines and one of signal lines is provided with two or three TFTs and also, a storage capacitor which is formed of a portion of a gate insulating layer sandwiched between its electrode and a preceding scanning line in the previous row with using no extra masking procedure. The source, drain and gate electrodes of both the first and third TFTs are coupled to the same signal line, the electrode of the same pixel and the adjacent scanning lines, respectively. The gate, source and drain electrodes of the second TFT are coupled respectively to the same scanning line to which the gate electrode of the first TFT is coupled, the electrode of the same pixel and the electrode of a succeeding pixel provided on the opposite side of the scanning line to the same pixel. The arrangement also has a scanning driver circuit capable of activating two scanning lines at the same time for sequential one-by-one scanning operation, whereby no fault in a reproduced image will be perceived in spite of the presence of a defective TFT.



#### **BACKGROUND OF THE INVENTION**

1.Fi ld of th Inv nti n

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The present invention relates t a liquid crystal display device using activ components.

#### 2.Description of the Prior Art

A known liquid crystal display device is provided with such an array of thin film transistors (abbreviated to "TFT" hereinafter) as shown in Fig.3 which is in more detail described in Japanese Patent Laid-open Publication 60-151615 (1985). The TFT array of the liquid crystal display device comprises a plurality of scanning lines X1 to XM (where M is the total number of the scanning lines), a plurality of signal lines X1 to XN (where N is the total number of the signal lines), a plurality of TFTs 11, and pixel electrodes 26. The scanning lines X1 to XM are coupled to gate electrodes 21 of their respective TFTs 11 and the signal lines Y1 to YN are coupled to source electrodes 23 of the same. The drain electrode 22 of each TFT 11 is coupled to a pixel electrode 26. A liquid crystal material 13 is sandwiched between the pixel electrode 26 and its opposite electrode 27 constituting a display pixel 14. The display pixel 14 acts as a capacitor in an equivalent circuit and if needed, may be accompanied with a storage capacitor coupled in parallel. The operation of the TFTs 11 will now be described referring to Fig.3. In operation, such selective pulses P1, P2, P3, ... as shown in Fig.4 are applied by a scanning driver circuit to the scanning lines X1, X2, X3, ... respectively. As shown in Fig.4, T represents a frame period while M is the number of the scanning lines. For example, when a pulse P1 only is fed, the scanning line X1 becomes activated selectively (while the other scanning lines remain unselected) thus allowing each of the TFTs 11 coupled thereto to be communicated between the source and the drain and draw a corresponding signal voltage from a signal driver circuit to actuate its pixel. When X1 is turned unselected, its TFTs become disconnected and hold their signal voltages applied to the pixels until X1 is again selected in the following frame. As understood, the liquid crystal display device with a TFT array is capable of feeding desired signal voltages to corresponding pixels accurately and respectively thus ensuring display of a picture which exhibits less crosstalk and high contrast ratio.

In production, it is however difficult to have a considerable number of finished TFTs qualified as "good" products, particularly when the number of their scanning and signal lines is increased. Each TFT is constructed in a layer arrangement in which the gate 21, the source 22, and the drain 23 are separated from each other by at least one insulating layer 24, as best shown in the cross sectional view of Fig.6. Hence, during a procedure of pinhole forming or other steps, any incidental error tends to cause shortcircuit between the gate and the source. Accordingly, the shortcircuit between the gate and source electrodes will result in crucial malfunction of a series of TFTs aligned along the scanning line coupled to the defective TFT which is known as "line defect". Also, when the source electrode 22 is shortcircuited to the drain electrode 23, their corresponding liquid crystal cell fails to hold a normal signal voltage thus causing "point defect".

An improved TFT array has also been introduced in which even if some TFTs are defective, pixel defects (including line defects and point defects) will be minimized, as disclosed in Japanese Patent Laid-open Publication 61-243483 (1986). The improved TFT array is illustrated in Fig.7 in which each pixel 14 incorporates a plurality of TFTs 11 so that even if one TFT is defective, the remaining TFTs can perform a normal action. However, when such a liquid crystal display device is used for display of alphabetic and numeric characters, the pixel capacitance has to be greater than a parasitic capacitance 28 for the purpose of temperature compensation or other compensation for signal noise and flicker effects. It is apparent that when the capacitance of each pixel 14 in the TFT array is adapted to be greater than the parasitic capacitance 28 of the TFT 11, no trouble arises. In practice, the pixel capacitance across a liquid crystal 13 is insufficient and noise pulses are inducted by a pixel potential via the parasitic capacitance 28 from the scanning line Xi (i=1 to M; M is the total number of the scanning lines) and the signal line Yj (j=1 to N: N is the total number of the signal lines). For solution, a storage capacitor is arranged in parallel to the display pixel in order to increase the pixel capacitance relative to the parasitic capacitance 28 and thus minimize the noise effect. It is well known that the storage capacitors are formed in an array between corresponding pixel electrodes 26 and a common electrode 28. Although this arrangement is advantageous in holding of signals, it will be disadvantageous in the cost of fabrication. More particularly, each storage capacitor in the TFT array is arranged by interposing an insulating layer between the pixel electrode 26 and the common electrode 29 and thus, requires an extra number of masking procedures during the production. As the result, a series of the masking procedures will cause the production cost to increase and incid ntally, the frequency of production faults will be increased.

## SUMMARY OF THE INVENTION

It is an object of thopresent invintion, in view of thoforegoing drawbacks, to provide a liquid crystal display device in which each disable pix I associated with at I ast in indifferent features an image segment which is equival nt in picture quality to that of a normal pixel. For the purpose, a TFT array, which comprises a plurality of scanning lines Xi (i=1 to M; M is the total number of the scanning lines), a plurality of signal lines Yj (j=1 to N; N is the total number of the signal lines), and a matrix of pixels, each pixel being disposed at the intersection of a scanning line and a signal line, is arranged in which each of the pixels is activated by the action of two or three TFTs and also, accompanied with a storage capacitor provided between its pixel electrode and the preceding scanning line (referred to the scanning line of the preceding row) selected before the current scanning line which is to be selected for energizing the pixel through the TFTs. Accordingly, there are provided two or three signal supply routes for each pixel and when an open circuit defect occurs in one of the TFTs, the corresponding pixel can be activated normally. In addition, the storage capacitor is arranged in parallel to the pixel so that the pixel capacitance can be increased for holding a signal voltage. Hence, the unwanted effect of another signal fed to an adjacent pixel, which is emphasized by the parasitic capacitance of the TFTs, will be minimized. Also, the storage capacitor is arranged between the scanning line of the preceding row and the pixel electrode so that it can be formed by a part of the insulating layer of the TFTs. As the result, the TFT array will be fabricated with no extra procedure during the production of the TFTs or more specifically, without the use of extra masking procedures.

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## **BRIEF DESCRIPTION OF THE DRAWINGS**

Fig.1 is an equivalent circuit diagram of a TFT liquid crystal display device showing one embodiment of the present invention;

Fig.2 is an equivalent circuit diagram of a TFT liquid crystal display device showing another embodiment of the present invention;

Fig.3 is an equivalent circuit diagram of a prior art liquid crystal display device;

Fig.4 is a waveform diagram of selective pulses used in a prior art;

Fig.5 is a waveform diagram of selective pulses used for selecting two consecutive scanning lines at the same time:

Fig.6 is a cross sectional view of a typical TFT; and

Fig.7 is an equivalent circuit diagram of another prior art liquid crystal display device.

## **DESCRIPTION OF THE PREFERRED EMBODIMENTS**

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According to the present invention, charging to each pixel coupled with one signal line and one scanning line is conducted by not a single TFT but two or three TFTs which provide their respective charging paths for input of signals. In addition, a storage capacitor is arranged between the pixel and its preceding scanning line. When any one of the two or two of the three TFTs of the pixel are found defective, they are separated from the pixel by e.g. laser cutting if in shortcircuit defect and left as they are if in open-circuit defect, while the remaining is substantially connected. Accordingly, the feeding of signals to a pixel electrode can be guaranteed. Since the line or point defects are avoided, the pixel will be energized without failure. Also, when the parasitic capacitance varies and causes a punch-through voltage to change during actuation of an operable TFT, the storage capacitor coupled between the pixel and its preceding scanning line in parallel to the pixel capacitance can constantly maintain the pixel capacitance greater than the parasitic capacitance thus minimizing unwanted effects caused by signal noise. As the result, the data of a normal signal will be supplied without deficiency. There is proposed a prior art in which for addition of such a redundant path, an extra TFT is arranged in parallel to a corresponding pixel. In that case, it will be difficult to identify one defective one from more than one of the TFTs for correction with the use of a laser device when a line or point defect has been detected. Also, another prior art arrangement is provided in which each pixel is associated with two scanning lines and incorporates two TFTs of which gate electrodes are coupled to the two scanning lines respectively. The disadvantage of this arrangement is that the pixel is sharply decreased in the aperture.

One preferred embodiment of the present invention will now be described referring to the accompanying drawings.

Fig.1 illustrates an quivalent circuit of th array arrangem nt of a TFT liquid crystal display device according to a first embodiment of th present invintion. In common, TFTs are composed of amorphous silicon, poly-crystalline silicon, and 2-6 semic inductor layers as shown in the cross sectional view of Fig.6. The waveform of a signal fed from a scanning driving recircuit to a scanning line X1-may be identical to that of a prin right art shown

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in Fig.4. Also, a driving method may be equal to that shown in Fig.5 in which scanning is overlapped by activating two scanning lines at the same tim . Wh in such a pulse as shown in Fig.5 is applied, a giv in number of th TFTs coupled t th two scanning lines are turned n. Then, signal voltages are supplied from a signal driv r circuit to all the signal lines in synchronization. Each pixel 14 of the liquid crystal display device of the present inv ntion, d n ted by (Ci,j), is arrang dat th intersecti n of n scanning line Xi (i=1 to M; M is th total numb r of the scanning lines) and one signal line Yj (j=1 to N; N is the total number of the signal lines) and activated through charging with the action of two TFTs 11a and 11c controlled by the scanning line Xi. The TFT 11a has a gate electrode 21a coupled to the scanning line Xi, a source electrode 23a coupled,to the signal line Yj, and a drain electrode 22a coupled to a pixel electrode 26 of the pixel 14 (Ci,j). Also, the TFT 11c has a gate electrode 21c coupled to the scanning line Xi, a source electrode 23c to the pixel electrode 26 of the pixel 14 (Ci,j), and a drain electrode 22c to the pixel electrode of another pixel 14 (Ci+1,j) arranged in the succeeding or next row. In addition, a storage capacitor 12 formed of e.g. SiNx, TaOx, SiOx, or AlOx material sandwiched between the pixel electrode 26 and the preceding scanning line Xi-1 is arranged in parallel to the pixel 14 (Ci,j). In operation, the pixel 14 (Ci,j) draws a signal a across TFTs 11a' and 11c' from the signal line Yj upon receiving an instruction pulse at the timing of selecting the scanning line Xi-1. The signal a is a voltage which is substantially designated for application to the pixel 14 (Ci-1,j). When the scanning line Xi is selected at the following timing, the pixel 14 (Ci,j) receives another instruction pulse and draws a signal b across the TFT 11a from the signal line Yj. Then, the pixel 14 (Ci,j) remains activated by the signal b until the scanning line Xi-1 is selected at another frame. Accordingly, such normal actions of the pixel will never be interrupted by the presence of the TFT 11c.

In case that the TFT 11a is shortcircuited, its drain electrode 22a is disconnected from the pixel electrode 26 by means of e.g. laser cutting. However, it is left intact when the defect is attributed to open-circuit. At the time, the signal b of the signal line Yj is transmitted from the TFT 11c to the next pixel 14 (Ci+1,j) with the timing of selection of the scanning line Xi, thus causing a point defect on the pixel 14 (Ci,j). Even if the TFT 11c is defective, the pixel 14 (Ci,j) operates correctly and the pixel 14 (Ci+1,j) substantially receives a signal c from a TFT 11a" thus operating normally. When the two adjacent scanning lines are simultaneously activated by two respective pulses shown in Fig.5, the pixel 14 (Ci,j) draws a substantial signal unless both the TFTs 11a and 11c become defective. More specifically, when the two scanning lines Xi-1 and Xi are selected, the signal a is transmitted from the pixel 14 (Ci-1,j) to the pixel 14 (Ci,j) by way of two routes across the TFT 11a and across the two TFTs 11a' and 11c'. Then, when the two scanning lines Xi and Xi+1 are selected at the next timing, the signal b is transmitted to the pixel 14 (Ci,j) by way of two routes across the TFT 11a and across the two TFTs 11a" and 11c. Accordingly, unless all of the three TFTs 11a, 11b, and 11c become defective at once, the substantial signal can be kept supplied. Also, the storage capacitor 12 arranged in parallel to the pixel 14 (Ci,j) is interposed between the pixel electrode 26 and the scanning line Xi-1 so that unwanted effects of a parasitic capacitance developed by the TFTs 11a, 11b, and 11c can be eliminated.

The foregoing assignment of signals are illustratively expressed in Tables 1 and 2.

TABLE 1 Sequencial Activation of Prior Art (One-scanning line drive)

Pixel Ci+1, j Pixel Ci-1, J Pixel Ci,j Remarks No. Normal **Hormal Action** a →b b→c →a a → leak leak→c No good 2 Fault on TFT11a  $\rightarrow a$ Normal Fault on TFT11c a →b →C →a

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TABLE 2 Sequencial Activation of Two Scanning Lines

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No.		Pixel Ci-1.j	Pixel Ci, J	Pixel Ci+1, j	Remarks
1	Normal Action	→a'→a	a'→a →b	a→ b→c	Normal
2	Fault on TFT11a	→a'→a	a°→a →b	a→ b→c	Normai
3	Fault on TFT11c	→a'→a	a'→a →b	b→c	Normal

If the probability of occurrence of the TFT's defect is P, the occurrence of a pixel defect will approximate to P in the prior art. According to the present invention, no pixel defect is involved unless the two TFTs associated with to one pixel become defective at the same time. Hence, the occurrence of a pixel defect is expressed by the order of P\*P. P is of the order of 1 ppm and then, P\*P becomes a quite small number. It is now understood that the yield of TFT array boards according to the present invention will be much increased.

The present invention provides a simple but improved arrangement of the TFT array which yields a higher operative reliability and thus, will be suited for practical use. Also, each storage capacitor is arranged between the pixel and its preceding scanning line so that it can be built in the TFT array without increasing the number of masking procedures. In practice, the storage capacitor is formed of an insulating layer which also serves as the gate insulator of a TFT, sandwiched between a pixel electrode and a gate scanning line. As the result, no extra procedure is needed during the production and thus, the production cost will be no more increased. The overall capacitance is also increased thus enhancing the quality of a reproduced image.

Another embodiment of the present invention will then be described in the form of a liquid crystal display device referring to the drawings. Fig.2 is an equivalent circuit diagram of the liquid crystal display device which comprises a plurality of scanning lines Xi (i=1 to M; M is the total number of the scanning lines) coupled to a scanning driver circuit, a plurality of signal lines Yj (j=1 to N; N is the total number of the signal lines) coupled to a signal driver circuit, and a plurality of pixels 14 denoted by (Ci,j), each being associated with both one scanning line Xi and one signal line Yj. Each pixel 14 (Ci,j) is arranged for drawing a signal from the signal line Yj by the action of three TFTs 11a, 11b, and 11c controlled by the scanning line Xi. All the TFTs are coupled at the gate electrode to the scanning line Xi. Both the source electrodes 23a and 23b of the their respective TFTs 11a and 11b are coupled to the signal line Yj. The drain electrodes 22a and 22c of the their respective TFTs 11a and 11c are coupled to a pixel electrode 26 of the pixel 14 (Ci,j). Also, the source electrode 23c of the TFT 11c is coupled to the pixel electrode 26 of the pixel 14 (Ci,j). The drain electrode 22c of the TFT 11c is coupled to the pixel elecrode of another pixel 14 (Ci+1,j) arranged in the succeeding or next row. In addition, a storage capacitor 12 formed of e.g. SiNx, TaOx, SiOx, or AlOx material is sandwiched between the pixel electrode 26 and the preceding scanning line Xi-1. In operation, such a series of signal pulses as shown in Fig.4 or 5 are supplied to the scanning lines respectively and synchronously, a signal voltage is transmitted from the signal driver circuit to each of the signal lines. The pixel 14 (Ci,j) draws a signal voltage via TFTs 11a' and 11c' from the signal line Yj at the timing of selecting the scanning line Xi-1. The signal a is a voltage substantially designated for application to the pixel 14 (Ci-1,j). When the scanning line Xi is selected at the following timing, the pixel 14 (Ci,j) receives another instruction pulse and draws a signal b across the TFT 11a from the signal line Yj. Then, the pixel 14 (Ci,j) remains activated by the signal b until the scanning line Xi-1 is selected in the next frame. Accordingly, such normal actions of the pixel will never be interrupted by the presence of the TFT 11b or 11c.

In case that the TFT 11a is shortcircuited, its drain electrode 22a is disconnected from the pixel electrode 26 of the pixel 14 (Ci,j) by means of e.g. laser cutting. However, it is left intact when the defect is attributed to open-circuit. At the timing of sell cting the scanning line Xi, the substantial signal bis fed from the signal line Yj across the TFTs 11b and 11c to the pixel 14 (Ci,j). The pixel 14 (Ci,j) will draw a punch-through voltage as a veltage difference unless the TFTs 11a, 11b, and 11c are equivalent to the parasitic capacitances 10a, 10b, and 10c. According to the present invention, the pixel 14 (Ci,j) is accompanied with the storage capacitor 12

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so that the pix I capacitance remains greater than the total parasitic capacitance and can thus be operated normally with ut declination in the picture quality.

The activation of two scanning lines similar to that in the previous imbodiment having a couple of TFT for each pix I, as she with in Fig.5, with overlapping relationship will further minimize any unwanted perational failur.

The foregoing assignment of input signals, similar to that in the previous embodiment having two TFTs for one pixel, is illustratively expressed in Tables 3 and 4.

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No.

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Normal Action

Fault on TFT11a

Fault on TFT11c

Fault on TFT11b

fault on IFTs11a, 11c

fault on TFTs11a, 11b

fault on TFTs11b, 11c

TABLE 3 Sequencial Activation of Scanning Line

Pixel Ci,j

a→b

a→b

a→b

a→b

a→

a→ leak

a→b

Pixel Ci+1, j

b→c

b→c

b→c

b→c

b→c

→c

leak→c

Remarks

Normal

Normal

Normal

Normal

No good

No good

Normal

Pixel Ci-1, j

 $\rightarrow a$ 

→a

-→a

→a

 $\rightarrow a$ 

→a

→a

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TABLE 4 Sequencial Activation of Two Scanning Lines

5	No.		Pixel Ci-1,j	Pixel Ci,j	Pixel Ci+1.j	Remarks
10	-	Normal Action	→a'→a	a' →a ·→b	a→ b→c	For OA
	2	Fault on TFT11a	→a'→a	a'→a →b	a→ b→c	For OA
15	3	Fault on TFT11c	→a'→a	a'→a →b	a→ b→c	For OA
	4	Fault on TFT11b	→a'→a	a'→a →b	a→ b→c	For OA
20	5	Fault on TFTs11a.11c	→a°→a	a·→a	a→ b→c	For AV
	6	Fault on TFTs11a,11b	→a'→a	a'→a →b	a→ b→c	For OA
25	7	Fault on TFTs11b,11c	→a'→a	a'→a →b	b→c	For OA

In Table 4, the term OA represents "office automation" appropriated for display of alphabetic and numeral characters and the term AV represents "audio visual" appropriated for display of a TV image.

In case of No.5 of Table 3, the pixel 14 (Ci,j) cannot draw another signal after receiving the signal a because both the TFTs 11a and 11c are defective. Accordingly, the capacitance of the storage capacitor 12 acts as a parasitic capacitance to the TFT 11b thus causing the signal a to the pixel 14 (Ci,j) to be affected by a pulse for disabling the scanning line Xi-1. Also, in case of No.6 of Table 3, the signal a fed across the TFT 11c to the pixel 14 (Ci,j) will leak off causing a pixel defect. However, as apparent from Table 4, the interruption with an adjacent pixel signal in the case of No.5 will be lessened to a visually negligible level by simultaneous activation of the two scanning lines and the drawback in the case of No.6 will not be perceived when a normal signal is supplied by the same simultaneous activation.

If the probability of the TFT's on a substrate becoming defective is P, the occurrence of a pixel defect will approximate to P in the prior art. According to the present invention, no pixel defect is involved unless all of the three TFTs associated with to one pixel become defective at the same time. Hence, the occurrence of a pixel defect is expressed by the order of P\*P\*P. P is of the order of 1 ppm and then, P\*P\*P becomes a quite small number. It is now understood that the yield of TFT array according to the present invention will be much increased.

The present invention provides a simple but improved arrangement of the TFT array which yields a higher operative reliability and thus, will be suited for practical use with a liquid crystal display device for alphabetic and numeral display. Also, each storage capacitor is arranged between the pixel and its preceding scanning line so that it can be built in the TFT array without increasing the number of masking procedures. As the result, the picture quality in reproduction will be enhanced with no production cost increase.

## **Claims**

- A liquid crystal display d vice having an array of thin film transistors s rving as switch elements for activating pixels, comprising:
  - a plurality of signal lines Yj for supply of signals (where j=1 to N; N is the total number of the signal lines);

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a plurality f scanning lines Xi for control of the thin film transistors (where i=1 to M; M is the total number of the scanning lines);

a matrix f pixels C(i,j), each being disposed at an intersection of a scanning line Xi and a signal line Yj;

said pix I C(i,j) being provided with first and second switch el ments controll d by a scanning line Xi, in which source and drain electrodes of the first switch element are coupled to the signal line Yj and a pixel electrode of the pixel C(i,j), respectively, and gate, source and drain electrodes of the second switch element are coupled respectively to the scanning line Xi, the pixel electrode of the pixel C(i,j) and a pixel electrode of an adjacent pixel C(i+1,j) arranged on the opposite side of the scanning line Xi to the pixel C(i,j); and

said pixel C(i,j) being accompanied with a storage capacitor formed of a portion of a gate insulating layer of the thin film transistor sandwiched between its pixel electrode and a preceding scanning line Xi-1 for control of a preceding pixel C(i-1,j).

- 2. A liquid crystal display device according to Claim 1, wherein a scanning driver circuit is arranged for activating at the same time two scanning lines coupled to the gate electrode of the TFT, which is provided for controlling signal input to the pixel, so that a sequence of one-by-one scanning can be executed.
  - A liquid crystal display device having an array of thin film transistors serving as switch elements for activating pixels, comprising:

a plurality of signal lines Yj for supply of signals (where j=1 to N; N is the total number of the signal lines);

a plurality of scanning lines Xi for control of the thin film transistors (where i=1 to M; M is the total number of the scanning lines);

a matrix of pixels C(i,j), each being disposed at an intersection of a scanning line Xi and a signal line Yj;

said pixel C(i,j) being provided with first, second, and third switch elements controlled by the scanning line Xi, in which source and drain electrodes of the first switch element are coupled to the signal line Yj and a pixel electrode of the pixel C(i,j) respectively, gate, source and drain electrodes of the second switch element are coupled respectively to the scanning line Xi, the pixel electrode of the pixel C(i,j) and a pixel electrode of an adjacent pixel C(i+1,j) arranged on the opposite side of the scanning line Xi to the pixel C(i,j), and gate, source and drain electrodes of the third switch element are coupled respectively to a preceding scanning line Xi-1, the signal line Yj and the pixel electrode of the pixel C(i,j); and

said pixel C(i,j) being accompanied with a storage capacitor formed of a portion of a gate insulating layer of the thin film transistor sandwiched between its pixel electrode and the preceding scanning line Xi-1 for control of a preceding pixel C(i-1,j).

4. A liquid crystal display device according to Claim 3, wherein a scanning driver circuit is arranged for activating at the same time two scanning lines coupled to the gate electrode of the TFT, which is provided for controlling signal input to the pixel, so that a sequence of one-by-one scanning can be executed.

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FIG. 1

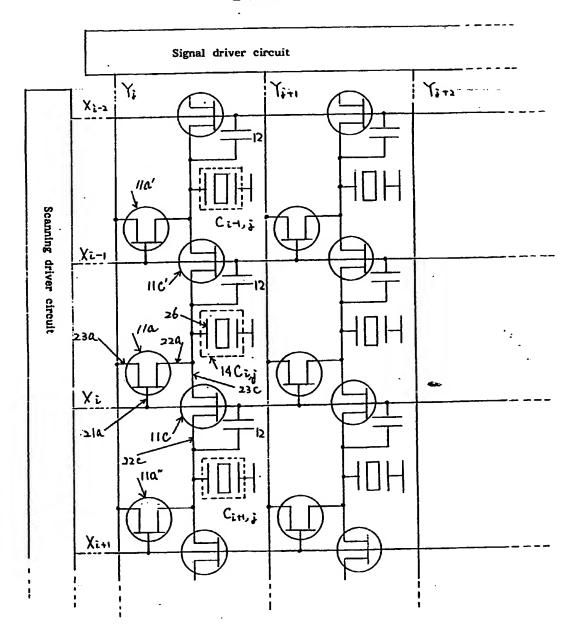
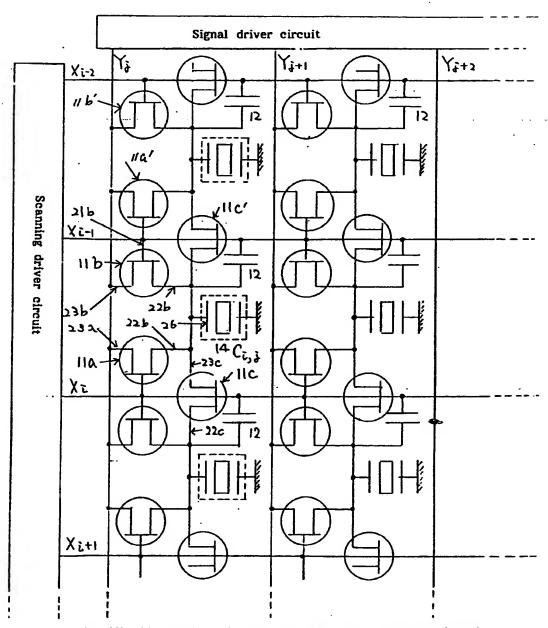


FIG.2



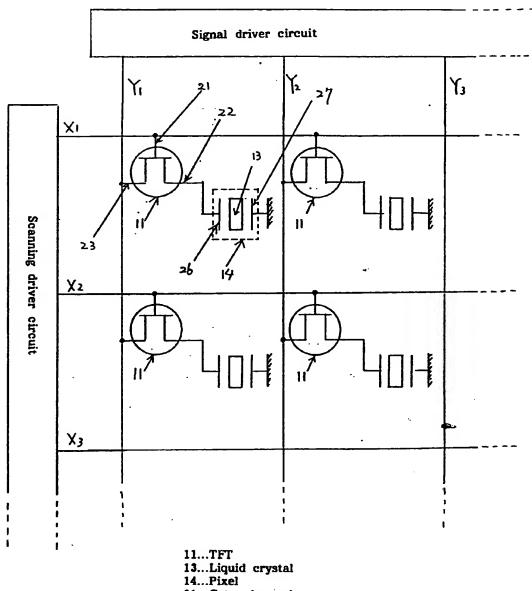
11a, 11b, 11c, 11a', 11b', and 11c'...Thin film transistors (TFTs) 12....Storage capacitor

14...Pixel

Xi...Scanning line

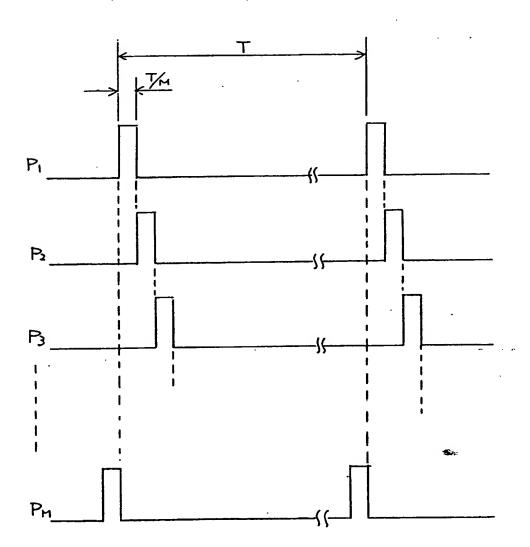
Yj...Signal line

FIG.3



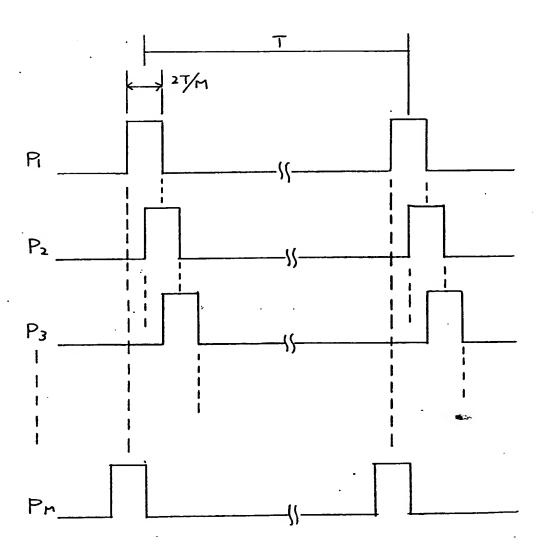
- 21...Gate electrode 22...Drain electrode
- 23...Source electrode
- 26...Pixel electrode
- 27...Opposite electrode
  X1, X2, X3, and so on...Scanning lines
  Y1, Y2, Y3, and so on...Signal lines

FIG. 4



T...One frame period M...Number of scanning lines

FIG.5



# FIG.6

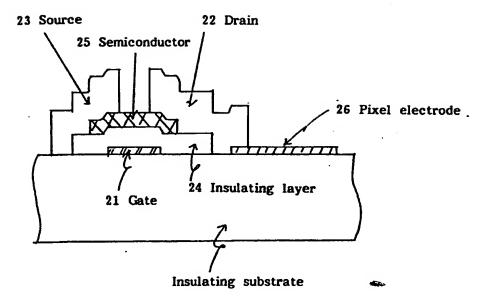


FIG.7

